Low-Voltage CMOS Octal Buffer

With 5 V-Tolerant Inputs and Outputs (3-State, Inverting)

The 74LVC240A is a high performance, inverting octal buffer operating from a 1.2 to 3.6 V supply. High impedance TTL compatible inputs significantly reduce current loading to input drivers while TTL compatible outputs offer improved switching noise performance. A $V_{\rm I}$ specification of 5.5 V allows 74LVC240A inputs to be safely driven from 5 V devices. The 74LVC240A is suitable for memory address driving and all TTL level bus oriented transceiver applications.

Current drive capability is 24 mA at the outputs. The Output Enable (\overline{OE}) input, when HIGH, disables the outputs by placing them in a HIGH Z condition.

Features

- Designed for 1.2 V to 3.6 V V_{CC} Operation
- 5 V Tolerant Interface Capability With 5 V TTL Logic
- Supports Live Insertion and Withdrawal
- I_{OFF} Specification Guarantees High Impedance When V_{CC} = 0 V
- 24 mA Output Sink and Source Capability
- Near Zero Static Supply Current in All Three Logic States (10 μA) Substantially Reduces System Power Requirements
- ESD Performance:
 - ♦ Human Body Model >2000 V
 - ◆ Machine Model >200 V
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant



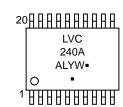
ON Semiconductor®

www.onsemi.com

MARKING DIAGRAM



TSSOP-20 DT SUFFIX CASE 948E



A = Assembly Location

L = Wafer Lot Y = Year W = Work Week ■ Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.

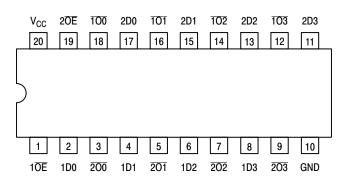
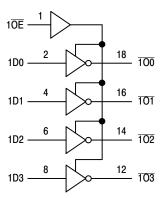


Figure 1. Pinout: 20-Lead (Top View)



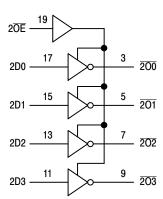


Figure 2. LOGIC DIAGRAM

PIN NAMES

Pins	Function
n OE	Output Enable Inputs
1Dn, 2Dn	Data Inputs
10n, 20n	3-State Outputs

TRUTH TABLE

INP	JTS	OUTPUTS
10E 20E	1Dn 2Dn	10n, 20n
L	L	Н
L	Н	L
Н	Х	Z

H = High Voltage Level
L = Low Voltage Level
Z = High Impedance State
X = High or Low Voltage Level

X = High or Low Voltage Level and Transitions Are Acceptable; for I_{CC} reasons, DO NOT FLOAT Inputs

MAXIMUM RATINGS

Symbol	Parameter	Condition	Value	Unit
V _{CC}	DC Supply Voltage		-0.5 to +6.5	V
VI	DC Input Voltage		$-0.5 \le V_1 \le +6.5$	V
Vo	DC Output Voltage	Output in 3-State	$-0.5 \le V_O \le +6.5$	V
		Output in HIGH or LOW State (Note 1)	$-0.5 \le V_{O} \le V_{CC} + 0.5$	V
I _{IK}	DC Input Diode Current	V _I < GND	-50	mA
I _{OK}	DC Output Diode Current	V _O < GND	-50	mA
		V _O > V _{CC}	+50	mA
Io	DC Output Source/Sink Current		±50	mA
Icc	DC Supply Current Per Supply Pin		±100	mA
I _{GND}	DC Ground Current Per Ground Pin		±100	mA
T _{STG}	Storage Temperature Range		-65 to +150	°C
T _L	Lead Temperature, 1 mm from Case for 10 Seconds		T _L = 260	°C
TJ	Junction Temperature Under Bias		T _J = 135	°C
$\theta_{\sf JA}$	Thermal Resistance (Note 2)		110.7	°C/W
MSL	Moisture Sensitivity	Level 1		

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Тур	Max	Units
V _{CC}	Supply Voltage Operating Functional	1.65 1.2		3.6 3.6	V
VI	Input Voltage	0		5.5	V
Vo	Output Voltage HIGH or LOW State 3–State	0		V _{CC} 5.5	V
I _{OH}	HIGH Level Output Current $V_{CC} = 3.0 \text{ V} - 3.6 \text{ V}$ $V_{CC} = 2.7 \text{ V} - 3.0 \text{ V}$			-24 -12	mA
I _{OL}	LOW Level Output Current $V_{CC} = 3.0 \text{ V} - 3.6 \text{ V}$ $V_{CC} = 2.7 \text{ V} - 3.0 \text{ V}$			24 12	mA
T _A	Operating Free–Air Temperature	-40		+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate V _{CC} = 1.65 V to 2.7 V V _{CC} = 2.7 V to 3.6 V	0 0		20 10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

^{1.} I_O absolute maximum rating must be observed.

^{2.} Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

DC ELECTRICAL CHARACTERISTICS

			-4	0°C to +8	5°C	-40	°C to +12	5°C	
Symbol	Parameter	Conditions	Min	Typ (Note 3)	Max	Min	Typ (Note 3)	Max	Unit
VIH	HIGH-level input	V _{CC} = 1.2 V	1.08	-	-	1.08	-	-	V
	voltage	V _{CC} = 1.65 V to 1.95 V	0.65 x V _{CC}	_	-	0.65 x V _{CC}	-	-	
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	-	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2.0	-	_	2.0	_	-	
V_{IL}	LOW-level input	V _{CC} = 1.2 V	-	-	0.12	-	_	0.12	V
	voltage	V _{CC} = 1.65 V to 1.95 V	-	_	0.35 x V _{CC}	-	-	0.35 x V _{CC}	
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	_	-	0.7	
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	_	-	0.8	
V _{OH}	HIGH-level output	$V_I = V_{IH}$	or V _{IL}	•					V
	voltage	$I_O = -100 \mu\text{A};$ $V_{CC} = 1.65 \text{V} \text{ to } 3.6 \text{V}$	V _{CC} - 0.2	_	-	V _{CC} - 0.3	-	-	
		$I_O = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	_	1.05	-	_	
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.8	-	_	1.65	-	_	
		$I_O = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	_	2.05	-	_	
		$I_O = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	-	_	2.25	-	_	
		$I_O = -24$ mA; $V_{CC} = 3.0$ V	2.2	-	_	2.0	-	_	
VOL	LOW-level output	$V_I = V_{IH}$	or V _{IL}						V
	voltage	$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	-	_	0.2	_	-	0.3	
		$I_O = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	_	-	0.65	
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.6	_	-	0.8	
		$I_{O} = 12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	1	_	0.4	_	-	0.6	
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	1	_	0.55	_	_	0.8	
I _I	Input leakage current	$V_I = 5.5 V$ or GND $V_{CC} = 3.6 V$	ı	±0.1	±5	_	±0.1	±20	μΑ
l _{OZ}	OFF-state output current	VI = VIH or VIL; $V_O = 5.5 \text{ V or GND}; V_{CC} = 3.6 \text{ V}$	-	±0.1	±5	_	±0.1	±20	μΑ
l _{OFF}	Power-off leakage current	V_{I} or $V_{O} = 5.5 \text{ V}$; $V_{CC} = 0.0 \text{ V}$	-	±0.1	±10	_	±0.1	±20	μА
I _{CC}	Supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 3.6 \text{ V}$	-	0.1	10	-	0.1	40	μΑ
Δl _{CC}	Additional supply current	per input pin; $V_1 = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	5	500	-	5	5000	μΑ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. All typical values are measured at $T_A = 25^{\circ}C$ and $V_{CC} = 3.3$ V, unless stated otherwise.

AC ELECTRICAL CHARACTERISTICS ($t_R = t_F = 2.5 \text{ ns}$)

			-40	°C to +8	5°C	-40°	°C to +12	25°C	
Symbol	Parameter	Conditions	Min	Typ ¹	Max	Min	Typ ¹	Max	Unit
t _{pd}	Propagation Delay (Note 5)	V _{CC} = 1.2 V	-	16.0	-	-	_	-	ns
	INDIT TO NOT	V _{CC} = 1.65 V to 1.95 V	1.0	5.7	12.7	1.0	_	14.6	
		V _{CC} = 2.3 V to 2.7 V	0.5	3.0	6.6	0.5	_	7.6	
		V _{CC} = 2.7 V	1.5	3.1	7.0	1.5	_	9.0	
		V _{CC} = 3.0 V to 3.6 V	1.3	2.6	5.5	1.3	_	7.0	
t _{en}	Enable Time (Note 6)	V _{CC} = 1.2 V	-	19.0	-	-	_	-	ns
	nOE to nOn	V _{CC} = 1.65 V to 1.95 V	1.5	6.3	15.9	1.5	-	18.3	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.5	3.6	8.8	1.5	-	10.1	
		V _{CC} = 2.7 V	1.0	3.7	8.5	1.0	-	11.0	
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$	1.1	2.9	7.0	1.1	-	9.0	
t _{dis}	Disable Time (Note 7)	V _{CC} = 1.2 V	-	17.0	_	-	-	-	ns
	INDE TO NON	V _{CC} = 1.65 V to 1.95 V	2.3	4.1	9.9	2.3	-	11.4	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.0	3.4	5.6	1.0	-	6.5	
		V _{CC} = 2.7 V	1.5	3.1	7.5	1.5	_	9.5	
		V _{CC} = 3.0 V to 3.6 V	1.4	2.9	6.0	1.4	_	7.5	
t _{sk(0)}	Output Skew Time (Note 8)		-	-	1.0	-	-	1.5	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

- 4. Typical values are measured at TA = 25°C and Vcc = 3.3 V, unless stated otherwise.
- 5. t_{pd} is the same as t_{PLH} and t_{PHL}.
- 6. t_{en} is the same as t_{PZL} and t_{PZH}.
- 7. t_{dis} is the same as t_{PLZ} and t_{PHZ} .
- 8. Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.

DYNAMIC SWITCHING CHARACTERISTICS

			T _A = +25°C			
Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OLP}	Dynamic LOW Peak Voltage (Note 9)	$\begin{array}{c} V_{CC} = 3.3 \text{ V, } C_L = 50 \text{ pF, } V_{IH} = 3.3 \text{ V, } V_{IL} = 0 \text{ V} \\ V_{CC} = 2.5 \text{ V, } C_L = 30 \text{ pF, } V_{IH} = 2.5 \text{ V, } V_{IL} = 0 \text{ V} \end{array}$		0.8 0.6		V
V _{OLV}	Dynamic LOW Valley Voltage (Note 9)	$\begin{aligned} &V_{CC} = 3.3 \text{ V, } C_L = 50 \text{ pF, } V_{IH} = 3.3 \text{ V, } V_{IL} = 0 \text{ V} \\ &V_{CC} = 2.5 \text{ V, } C_L = 30 \text{ pF, } V_{IH} = 2.5 \text{ V, } V_{IL} = 0 \text{ V} \end{aligned}$		-0.8 -0.6		V

^{9.} Number of outputs defined as "n". Measured with "n-1" outputs switching from HIGH-to-LOW or LOW-to-HIGH. The remaining output is measured in the LOW state.

CAPACITIVE CHARACTERISTICS

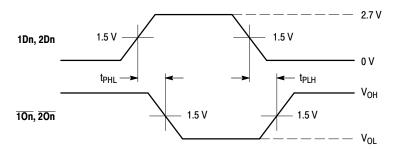
Symbol	Parameter	Condition	Typical	Unit	
CIN	Input Capacitance	$V_{CC} = 3.3 \text{ V}, V_{I} = 0 \text{ V or } V_{CC}$	5.0	pF	
Соит	Output Capacitance	$V_{CC} = 3.3 \text{ V}, V_I = 0 \text{ V or } V_{CC}$	7.0	pF	
C_{PD}	Power Dissipation Capacitance	Per input; V _I = GND or V _{CC}			
	(Note 10)	V _{CC} = 1.65 V to 1.95 V	2.0		
		V _{CC} = 2.3 V to 2.7 V	5.2		
		V _{CC} = 3.0 V to 3.6 V	8.1		

^{10.} C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times \text{fi x N} + \Sigma (C_L \times V_{CC}^2 \times \text{fo)}$ where: fi = input frequency in MHz; fo = output frequency in MHz C_L = output load capacitance in pF V_{CC} = supply voltage in Volts

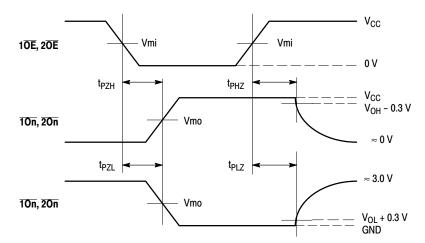
N = number of outputs switching

 $[\]Sigma(C_L \times V_{CC}^2 \times fo) = \text{sum of the outputs.}$



WAVEFORM 1 - PROPAGATION DELAYS

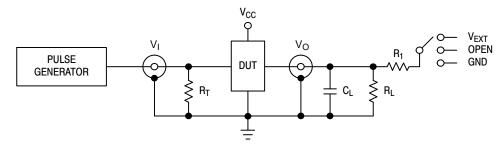
 $t_R = t_F = 2.5 \text{ ns}, 10\% \text{ to } 90\%; f = 1 \text{ MHz}; t_W = 500 \text{ ns}$



WAVEFORM 2 – OUTPUT ENABLE AND DISABLE TIMES $t_R = t_F = 2.5 \ \text{ns}, \ 10\% \ \text{to} \ 90\%; \ f = 1 \ \text{MHz}; \ t_W = 500 \ \text{ns}$

Figure 3. AC Waveforms

	V _{CC}						
Symbol	3.3 V \pm 0.3 V	2.7 V	V _{CC} < 2.7 V				
Vmi	1.5 V	1.5 V	V _{CC} /2				
Vmo	1.5 V	1.5 V	V _{CC} /2				
V _{HZ}	V _{OL} + 0.3 V	V _{OL} + 0.3 V	V _{OL} + 0.15 V				
V_{LZ}	V _{OH} – 0.3 V	V _{OH} – 0.3 V	V _{OH} – 015 V				



 C_L includes jig and probe capacitance R_T = Z_{OUT} of pulse generator (typically 50 $\Omega)$ R_1 = R_L

Supply Voltage	Inj	put	Lo	ad	V _{EXT}		
V _{CC} (V)	VI	t _r , t _f	CL	R _L	t _{PLH} , t _{PHL}	t _{PLZ} , t _{PZL}	t _{PHZ} , t _{PZH}
1.2	V _{CC}	≤ 2 ns	30 pF	1 kΩ	Open	2 x V _{CC}	GND
1.65 – 1.95	V _{CC}	≤ 2 ns	30 pF	1 kΩ	Open	2 x V _{CC}	GND
2.3 – 2.7	V _{CC}	≤ 2 ns	30 pF	500 Ω	Open	2 x V _{CC}	GND
2.7	2.7 V	≤ 2.5 ns	50 pF	500 Ω	Open	2 x V _{CC}	GND
3 – 3.6	2.7 V	≤ 2.5 ns	50 pF	500 Ω	Open	2 x V _{CC}	GND

Figure 4. Test Circuit

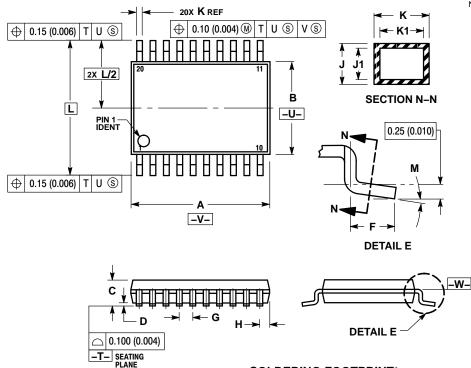
ORDERING INFORMATION

Device	Package	Shipping [†]
74LVC240ADTR2G	TSSOP-20 (Pb-Free)	2500 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

TSSOP-20 CASE 948E-02 **ISSUE C**



- NOTES:

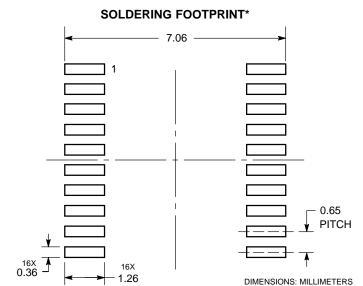
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION:
 MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
 5. DIMENSION K DOES NOT INCLUDE

 - 5. DIMENSION K DOES NOT INCLUDE
 DAMBAR PROTRUSION. ALLOWABLE
 DAMBAR PROTRUSION SHALL BE 0.08
 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL
 - CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE —W.—.

DETERMINED AT DATOWIF LAINE -W								
	MILLIN	IETERS	INC	HES				
DIM	MIN	MAX	MIN	MAX				
Α	6.40	6.60	0.252	0.260				
В	4.30	4.50	0.169	0.177				
С		1.20		0.047				
D	0.05	0.15	0.002	0.006				
F	0.50	0.75	0.020	0.030				
G	0.65	BSC	0.026 BSC					
Н	0.27	0.37	0.011	0.015				
7	0.09	0.20	0.004	0.008				
J1	0.09	0.16	0.004	0.006				
K	0.19	0.30	0.007	0.012				
K1	0.19	0.25	0.007	0.010				
L	6.40		0.252 BSC					
М	0°	8°	0°	8°				



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and the IIII are registered trademarks of Semiconductor Components Industries, LLC (SCILLC) or its subsidiaries in the United States and/or other countries. SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC date seets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor 19521 E. 32nd Pkwy, Aurora, Colorado 80011 USA **Phone**: 303–675–2175 or 800–344–3860 Toll Free USA/Canada **Fax**: 303–675–2176 or 800–344–3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada Europe, Middle East and Africa Technical Support:

Phone: 421 33 790 2910

Japan Customer Focus Center Phone: 81-3-5817-1050

ON Semiconductor Website: www.onsemi.com

Order Literature: http://www.onsemi.com/orderlit

For additional information, please contact your local Sales Representative